

TYPES 2N2639 THRU 2N2644 DUAL N-P-N SILICON TRANSISTORS

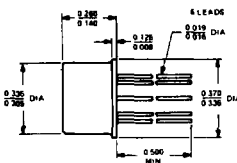
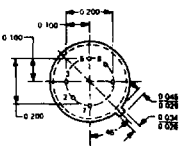
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TWO TRANSISTORS IN ONE PACKAGE RECOMMENDED FOR

- Differential Amplifiers
- High-Gain, Low-Noise Audio Amplifiers
- Transducer Signal-Conditioner Amplifiers
- Low-Level Flip-Flops

*mechanical data


ALL LEADS INSULATED FROM CASE

ALL DIMENSIONS ARE IN INCHES
UNLESS OTHERWISE SPECIFIED

Dimensions without tolerance designate true position. Leads having maximum diameter (0.019") measured in gaging plane 0.054" +0.001" -0.000" below the seating plane of the device shall be within 0.007" of their true position relative to a maximum width tab.

1. COLLECTOR 1
2. BASE 1
3. EMITTER 1
5. EMITTER 2
6. BASE 2
7. COLLECTOR 2



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*absolute maximum ratings at 25°C free-air temperature (unless otherwise noted)

	EACH TRIODE	TOTAL DEVICE
Collector-Base Voltage	45 V	
Collector-Emitter Voltage (See Note 1)	45 V	
Emitter-Base Voltage	5 V	
Continuous Collector Current	30 mA	
Continuous Device Dissipation at (or below) 25°C Free-Air Temperature (See Note 2)	0.3 W	0.6 W
Continuous Device Dissipation at (or below) 25°C Case Temperature (See Note 3)	0.6 W	1.2 W
Storage Temperature Range	-65°C to 200°C	
Lead Temperature 1/16 Inch from Case for 10 Seconds	← 300°C →	

- NOTES: 1. This value applies when the emitter-base diode is open-circuited.
 2. For each triode derate linearly to 175°C free-air temperature at the rate of 2 mW/°C.
 3. For each triode derate linearly to 175°C case temperature at the rate of 4 mW/°C.

*JEDEC registered data. This data sheet contains all applicable registered data in effect at the time of publication.

USES CHIP N11

TYPES 2N2639 THRU 2N2644

DUAL N-P-N SILICON TRANSISTORS

*electrical characteristics at 25°C free-air temperature (unless otherwise noted)

individual triode characteristics (see note 4)

PARAMETER	TEST CONDITIONS	2N2639	2N2642	UNIT		
		2N2640	2N2643			
		MIN	MAX			
$V_{(BR)CEO}$ Collector-Emitter Breakdown Voltage	$I_C = 10 \text{ mA}$, $I_B = 0$, See Note 5	45	45	V		
I_{CBO} Collector Cutoff Current	$V_{CB} = 45 \text{ V}$, $I_E = 0$	10	10	nA		
	$V_{CB} = 45 \text{ V}$, $I_E = 0$, $T_A = 150^\circ\text{C}$	10	10	μA		
I_{CEO} Collector Cutoff Current	$V_{CE} = 5 \text{ V}$, $I_B = 0$	10	10	nA		
I_{EBO} Emitter Cutoff Current	$V_{EB} = 5 \text{ V}$, $I_C = 0$	10	10	nA		
h_{FE} Static Forward Current Transfer Ratio	$V_{CE} = 5 \text{ V}$, $I_C = 10 \mu\text{A}$	50	300	100	300	
	$V_{CE} = 5 \text{ V}$, $I_C = 10 \mu\text{A}$, $T_A = -55^\circ\text{C}$	10	20			
	$V_{CE} = 5 \text{ V}$, $I_C = 100 \mu\text{A}$	55	110			
	$V_{CE} = 5 \text{ V}$, $I_C = 1 \text{ mA}$	65	130			
V_{BE} Base-Emitter Voltage	$I_B = 0.5 \text{ mA}$, $I_C = 10 \text{ mA}$	0.6	1	0.6	1	V
$V_{CE(sat)}$ Collector-Emitter Saturation Voltage	$I_B = 0.5 \text{ mA}$, $I_C = 10 \text{ mA}$	1	1			V
h_{ib} Small-Signal Common-Base Input Impedance		25	32	25	32	Ω
h_{rb} Small-Signal Common-Base Reverse Voltage Transfer Ratio	$V_{CB} = 5 \text{ V}$, $I_E = -1 \text{ mA}$, $f = 1 \text{ kHz}$	6 x 10 ⁻⁴	6 x 10 ⁻⁴			
h_{ob} Small-Signal Common-Base Output Admittance		1	1			μmho
h_{fe} Small-Signal Common-Emitter Forward Current Transfer Ratio	$V_{CE} = 5 \text{ V}$, $I_C = 1 \text{ mA}$, $f = 1 \text{ kHz}$	65	600	130	600	
$ h_{fe} $ Small-Signal Common-Emitter Forward Current Transfer Ratio	$V_{CE} = 5 \text{ V}$, $I_C = 1 \text{ mA}$, $f = 20 \text{ MHz}$	4	4			dB
C_{obo} Common-Base Open-Circuit Output Capacitance	$V_{CB} = 5 \text{ V}$, $I_E = 0$, $f = 1 \text{ MHz}$	8	8			μF

triode matching characteristics

PARAMETER	TEST CONDITIONS	2N2639	2N2640	UNIT		
		2N2642	2N2643			
		MIN	MAX			
h_{FE1} Static Forward-Current-Gain	$V_{CE} = 5 \text{ V}$, $I_C = 10 \mu\text{A}$, See Note 6	0.9	1	0.8	1	
h_{FE2} Balance Ratio						
$ V_{BE1} - V_{BE2} $ Base-Emitter-Voltage Differential	$V_{CE} = 5 \text{ V}$, $I_C = 10 \mu\text{A}$	5	10			mV
$\frac{ \Delta(V_{BE1} - V_{BE2}) }{\Delta T_A}$ Base-Emitter-Voltage-Differential Temperature Gradient	$V_{CE} = 5 \text{ V}$, $I_C = 10 \mu\text{A}$ $\Delta T_A = [25^\circ\text{C} - (-55^\circ\text{C})]$ and $[125^\circ\text{C} - 25^\circ\text{C}]$	10	20			$\mu\text{V}/^\circ\text{C}$

*operating characteristics at 25°C free-air temperature

individual triode characteristics (see note 4)

PARAMETER	TEST CONDITIONS	ALL TYPES	UNIT
		MAX	
\bar{F} Average Noise Figure	$V_{CB} = 5 \text{ V}$, $I_E = -10 \mu\text{A}$, $R_G = 10 \text{ k}\Omega$, Noise Bandwidth = 15.7 kHz, See Note 7	4	dB

NOTES: 4. The terminals of the triode nct under test are open-circuited for the measurement of these characteristics.

5. This parameter must be measured using pulse techniques. $t_w = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

6. The lower of the two h_{FE} readings is taken as h_{FE1} .

7. Average Noise Figure is measured in an amplifier with response down 3 dB at 10 Hz and 10 kHz and a high-frequency rolloff of 6 dB/octave.

*JEDEC registered data

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